Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1 - 3. (Canceled)

4. (Currently amended) A semiconductor integrated circuit device comprising:

an output portion arranged to provide ~~that outputs~~ via a switch element a predetermined voltage to an outside from a voltage output terminal through a voltage output line; and

a control portion to perform ~~that performs~~ predetermined control based on a control signal ~~inputted~~ from outside to a signal input line or a signal input terminal that is ~~so arranged as to be~~ adjacent to the voltage output line or the voltage output terminal,

~~wherein there is provided~~ a voltage detection portion ~~that detects~~ arranged to detect that a voltage higher than a reference voltage is ~~inputted~~ provided to the signal input line or the signal input terminal and arranged to feed ~~feeds~~ a resultant voltage to the output portion as a voltage detection signal, wherein the voltage detection portion includes:

a first transistor arranged to turn on when a voltage at the signal input terminal is higher than the reference voltage, and

a second transistor that forms a current mirror circuit together with the first transistor, and

wherein the voltage detection portion is arranged to provide the voltage detection signal from a node at which a resistor that pulls up the second transistor and the second transistor are connected together, and

wherein the output portion is arranged to open ~~opens~~ the switch element when the voltage detection signal is provided thereto.

5. (Currently amended) The semiconductor integrated circuit device of claim 4,

wherein the output portion includes:

a drive circuit arranged to generate ~~that generates~~ a driving signal for driving the switch element, and

a logic gate arranged to take ~~that takes~~ an AND of the driving signal and the voltage detection signal and then to feed ~~feeds~~ a resulting output to a control terminal of the switch element.

6. (Canceled)

7. (Currently amended) The semiconductor integrated circuit device of claim 4 [[6]],

wherein the voltage detection portion further includes a diode in a current path between the signal input terminal and the first transistor, and

wherein the voltage detection portion is arranged such that a value obtained by adding a forward voltage of the diode and a base-emitter voltage of the first transistor is equivalent to the reference voltage.

8. (Canceled)

9. (Currently amended) The semiconductor integrated circuit device of claim 4 [[1]],

wherein a breakdown voltage of the switch element is higher than a breakdown voltage of the control portion.

10. (Canceled)